

# Monolithic Dual Switching Diodes

## FETURE

- Pb-Free Package is available.

## ORDERING INFORMATION

Device	Marking	Shipping
LMBD2837LT1	A5	3000/Tape&Reel
LMBD2837LT1G	A5(Pb-Free)	3000/Tape&Reel
LMBD2838LT1	MA6	3000/Tape&Reel
LMBD2838LT1G	MA6(Pb-Free)	3000/Tape&Reel

## MAXIMUM RATINGS(EACH DIODE)

Rating	Symbol	Value	Unit
Peak Reverse Voltage	V <sub>RM</sub>	75	Vdc
D.C Reverse Voltage	LMBD2837LT1	30	Vdc
	LMBD2838LT1	50	
Peak Forward Current	I <sub>FM</sub>	450	mAdc
		300	
Average Rectified Current	I <sub>o</sub>	150	mAdc
		100	

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board <sup>(1)</sup>	P <sub>D</sub>	225	mW
T <sub>A</sub> = 25°C			
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	556	°C/W
Total Device Dissipation	P <sub>D</sub>	300	mW
Alumina Substrate, <sup>(2)</sup> T <sub>A</sub> = 25°C			
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

## DEVICE MARKING

LMBD2837LT1 = A5; LMBD2838LT1 = MA6

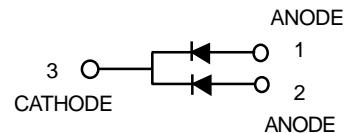
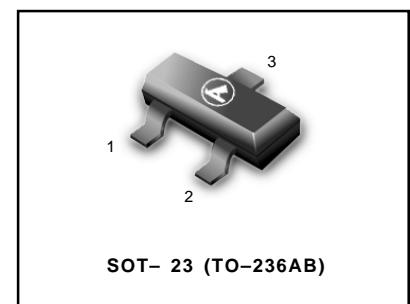
## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted) ( EACH DIODE )

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Reverse Breakdown Voltage(I <sub>(BR)</sub> = 100μAdc)	LMBD2837LT1	V <sub>(BR)</sub>	35	—
	LMBD2838LT1		75	—
Reverse Voltage Leakage Current (V <sub>R</sub> = 30 Vdc)	I <sub>R</sub>	—	—	μAdc
(V <sub>R</sub> = 50 Vdc)	LMBD2837LT1		0.1	
LMBD2838LT1			0.1	
Diode Capacitance (V <sub>R</sub> = 0 V, f = 1.0 MHz)	C <sub>T</sub>	—	4.0	pF
Forward Voltage(I <sub>F</sub> = 10 mA)	V <sub>F</sub>	—	1.0	Vdc
(I <sub>F</sub> = 50 mA)			1.0	
(I <sub>F</sub> = 100 mA)			1.2	
Reverse Recovery Time(I <sub>F</sub> =I <sub>R</sub> =10mA, I <sub>R(REC)</sub> =1.0mA)(Figure 1)	t <sub>rr</sub>	—	4.0	ns

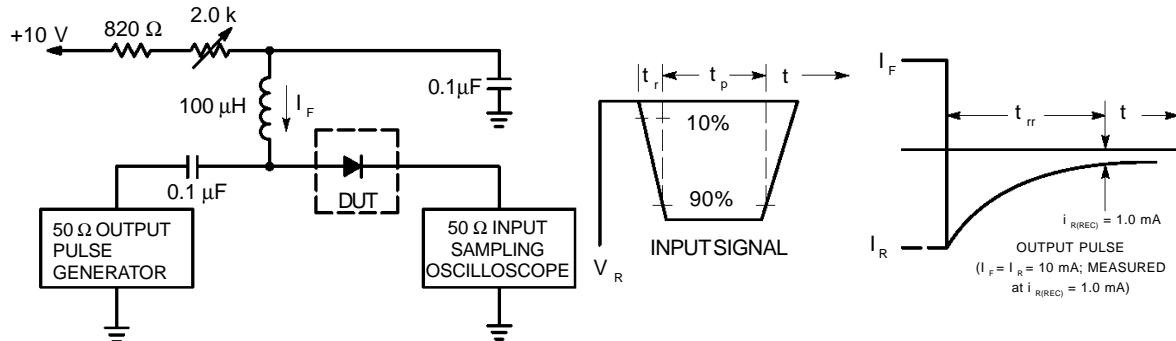
1. FR-5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

**LMBD2837LT1**  
**LMBD2838LT1**



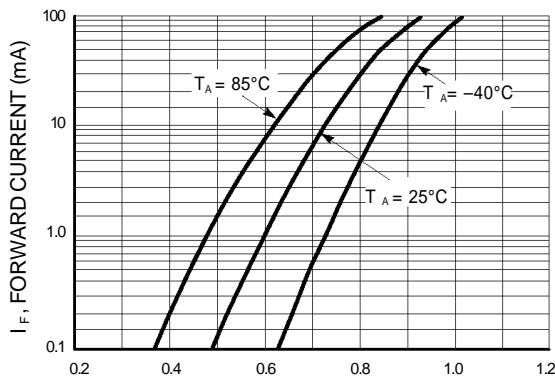
## **LMBD2837LT1 LMBD2838LT1**



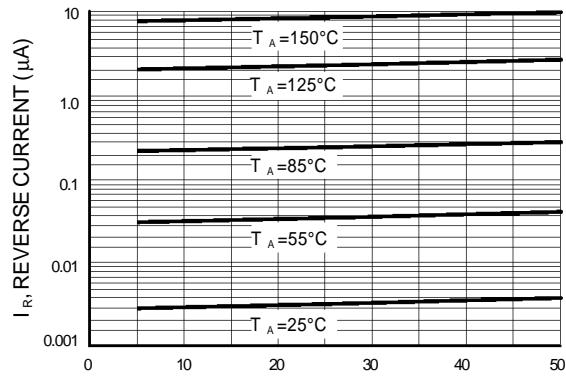
- Notes:
1. A 2.0 kΩ variable resistor adjusted for a Forward Current ( $I_F$ ) of 10mA.
  2. Input pulse is adjusted so  $I_{R(\text{peak})}$  is equal to 10mA.
  3.  $t_p \gg t_{rr}$

**Figure 1. Recovery Time Equivalent Test Circuit**

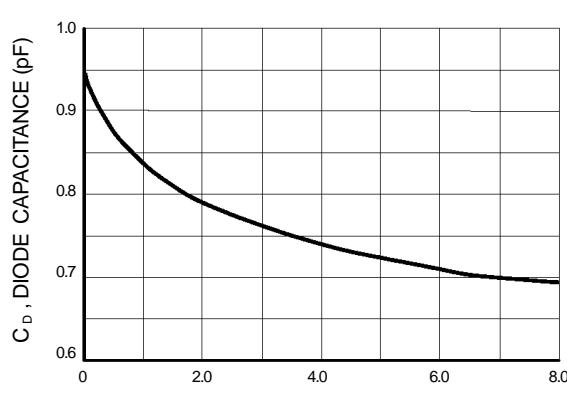
### CURVES APPLICABLE TO EACH CATHODE



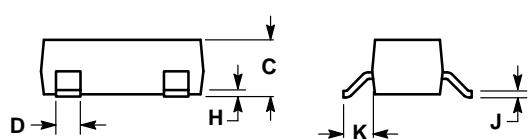
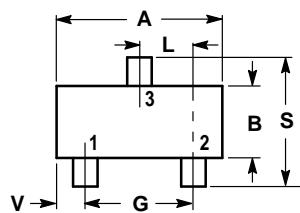
**Figure 2. Forward Voltage**



**Figure 3. Leakage Current**



**Figure 4. Capacitance**

**LMBD2837LT1 LMBD2838LT1**
**SOT-23**

**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

PIN 1. ANODE  
 2. NO CONNECTION  
 3. CATHODE

